

1. Features and Benefits

- Programmable high-speed current sensor
- Programmable linear transfer characteristic
- Selectable analog ratiometric output
- Measurement range from 15 to 450 mT
- Single die VA package RoHS compliant
- Suitable for lead free soldering profile 260°C (target), MSL1
- Wideband: DC to 250kHz
- Short response time 2μsec
- AEC-Q100 Automotive Qualified

2. Application Examples

- Inverter applications in HEV and EV
- BLDC motor current monitoring
- AC/DC converters
- Over current detection circuit

3. General Description

The MLX91209 is a monolithic programmable Hall sensor IC featuring the planar Hall technology, which is sensitive to the flux density applied orthogonally to the IC surface. The sensor provides an output signal proportional to the applied magnetic flux density and is preferably suited for current measurement. The transfer characteristic of the MLX91209 is programmable (offset, gain). The linear analog output is designed for applications where a very fast response is required, such as inverter applications.

In a typical application, the sensor is used in combination with a ring shaped soft ferromagnetic core. The Hall IC is placed in a small air gap and the current conductor is passed through the inner part of the ferromagnetic ring. The ring concentrates and amplifies the magnetic flux on the Hall sensor IC, which generates an output voltage proportional to the current flowing in the conductor.

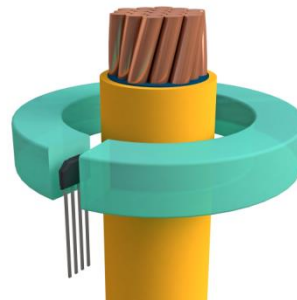


Figure 1: Typical Current Sensing Application

4. Ordering Information

Product	Temperature	Package	Option Code	Packing Form	Default Sensitivity
MLX91209	L (-40°C to 150°C)	VA	CAA - 000	BU/CR	50 mV/mT (prog: 5..150mV/mT)
MLX91209	L (-40°C to 150°C)	VA	CAA - 001	BU/CR	15 mV/mT (prog: 5..150mV/mT)
MLX91209	L (-40°C to 150°C)	VA	CAA - 002	BU/CR	7.3 mV/mT (prog: 5..150mV/mT)
MLX91209	L (-40°C to 150°C)	VA	CAA - 003	BU/CR	19 mV/mT (prog: 5..150mV/mT)
MLX91209	L (-40°C to 150°C)	VA	CAA - 005	BU/CR	8.78mV/mT (prog: 5..150mV/mT)
MLX91209	L (-40°C to 150°C)	VA	CAA - 006	BU/CR	6.9 mV/mT (prog: 5..150mV/mT)

Table 1: Ordering Information

Legend:

Temperature Code:	L	from -40°C to 150°C ambient temperature
Package Code:	VA	SIP4-VA package, refer to Chapter 19 for detailed drawings
Option Code:	CAx-000 CAx-001 CAx-002 CAx-003 CAx-005 CAx-006 CAA-xxx CAR-xxx CAZ-xxx	for factory trimmed sensitivity 50mV/mT (prog: 5..150mV/mT) for factory trimmed sensitivity 15mV/mT (prog: 5..150mV/mT) for factory trimmed sensitivity 7.3mV/mT (prog: 5..150mV/mT) for factory trimmed sensitivity 19mV/mT (prog: 5..150mV/mT) for factory trimmed sensitivity 8.78mV/mT (prog: 5..150mV/mT) for factory trimmed sensitivity 6.9mV/mT (prog: 5..150mV/mT) default straight leads (see chapter 19) Trim and Form shape: 90° 2x2x91.3 (h=5.34mm) Bending-STD2 (see chapter 19) Trim and Form shape: SMD style TFT4K1 (see chapter 19)
Packing Form:	BU CR CA RE	for Bulk, for Carton Reel - Radial taping – available for straight leads only for Carton Reel – Ammopack – available for straight leads only for Plastic Reel – available for selected Trim & Form options only
Ordering Example:	“MLX91209LVA-CAA-003-RE” MLX91209 Conventional Hall current sensor in SIP4 VA package, temperature range -40°C to 150°C. Sensitivity 19mV/mT. Parts delivered in Carton Reel (Radial Taping)	

Table 2: Legend for Ordering Information

Contents

1. Features and Benefits.....	1
2. Application Examples	1
3. General Description.....	1
4. Ordering Information	2
5. Glossary of Terms.....	4
6. Functional Diagram	4
7. Absolute Maximum Ratings.....	5
8. Pin Definitions and Descriptions.....	5
9. General Electrical Specifications.....	5
10. Magnetic specification	6
10.1. Sensor active measurement direction.....	7
11. Analog output specification.....	7
11.1. Timing specification.....	7
11.2. Accuracy specification	8
11.3. Remarks to the achievable accuracy	8
12. Programmable items.....	9
12.1. Parameter table.....	9
12.2. Sensitivity programming (RG, FG)	9
12.3. Offset / output quiescent voltage programming (VOQ)	9
12.4. Output ratiometry (ENRATIO)	9
12.5. Sensitivity temperature drift programming (TC1, TC2COLD, TC2HOT)	10
12.6. Offset temperature drift programming (OFFDR2C, OFFDR2H)	10
12.7. Noise filter (NOISEFILT).....	10
12.8. Identification code (ID)	10
13. Self-diagnostic.....	11
14. Recommended Application Diagrams.....	12
14.1. Resistor and capacitor values	12
14.2. Pull down resistor for diagnostic low	12
15. Typical performance.....	13
16. IC handling and assembly	14
16.1. Storage and handling of plastic encapsulated ICs	14
16.2. Assembly of encapsulated ICs	14
17. FAQ.....	15
18. Package Information	15
18.1. Package Marking & Hall Plate Position.....	15
18.2. VA / SIP 4L (single in-line package).....	16
18.3. Trim and form type: 90° 2x2x91.3 (h=5.34mm); Bending-STD2 (CAR-xxx)	16
18.4. Trim and form type: SMD style TFT4K1 (CAZ-xxx).....	17
19. Disclaimer.....	19

5. Glossary of Terms

Terms	Definition
Tesla	Units for the magnetic flux density, 1 mT = 10 Gauss
TC	Temperature Coefficient in ppm/deg C
NC	Not Connected
ADC	Analog to Digital Converter
DAC	Digital to Analog Converter
LSB	Least Significant Bit
MSB	Most Significant Bit
DNL	Differential Non Linearity
INL	Integral Non Linearity
IMC	Integrated Magneto Concentrator (IMC-Hall®)
PTC	Programming Through Connector

Table 3: Glossary of Terms

6. Functional Diagram

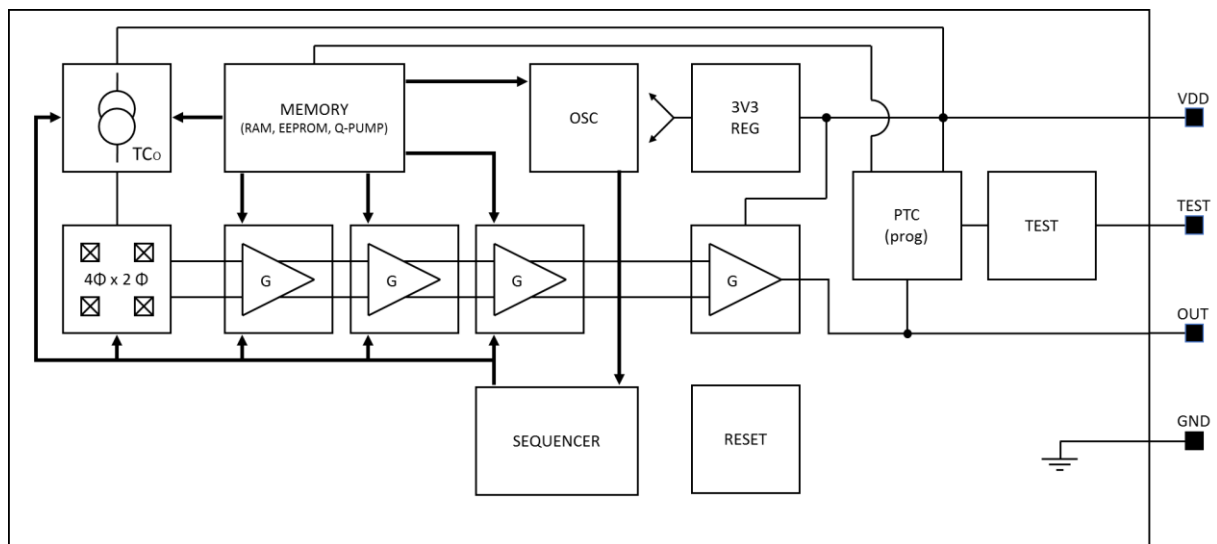


Figure 2: Block Diagram

7. Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Positive Supply Voltage (overvoltage)	V _{dd}	+10	V
Reverse Supply Voltage Protection		-0.3	V
Positive Output Voltage ⁽¹⁾		+10	V
Output Current	I _{out}	±70	mA
Reverse Output Voltage		-0.3	V
Reverse Output Current		-50	mA
Package Thermal Resistance (junction-to-ambient) θ_{ja} is defined according JEDEC 1s0p board	θ_{ja}	205	°C/W
Operating Ambient Temperature Range	T _A	-40 to +150	°C
Storage Temperature Range	T _S	-55 to +165	°C
Magnetic Flux Density		±3	T
Maximum Junction Temperature		-55 to 155	°C
ESD – Human Body Model (applicable for all pins)		2	kV

Table 4: Absolute maximum ratings

Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

(1) Valid for supply=10V or supply-pin floating.

8. Pin Definitions and Descriptions

Pin №	Name	Type	Function
1	VDD	Supply	Supply Voltage
2	OUT	Analog	Current Sensor Output
3	TEST/MUST	Digital	Test and Factory Calibration
4	GND	Ground	Supply Voltage

Table 5: Pin definitions and descriptions

It is recommended to connect the TEST/MUST pin to the Ground for optimal EMC performance.

9. General Electrical Specifications

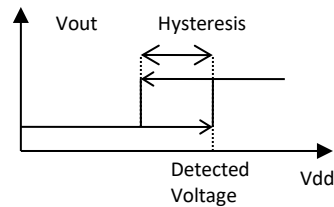
Operating Parameters: $T_A = -40^{\circ}\text{C}$ to 125°C , $V_{dd} = 4.5\text{V}$ to 5.5V , $I_{out} = -2\text{mA}$ to 2mA , recommended application diagram, unless otherwise specified.

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Nominal Supply Voltage	V_{dd}		4.5	5	5.5	V
Supply Current	I_{dd}	No output load, application mode, $T_A = -40^{\circ}\text{C}$ to 150°C	9	12	14	mA
DC Load Current	I_{out}	R_{load} in range [6k Ω , 100k Ω]	-2		2	mA
Maximum Output Current (driving capability)	I_{max}	Inside this range, output voltage reaches 3 and 97% V_{dd}	-2		2	mA
Output Resistance		$V_{out} = 50\% V_{dd}$, $R_L = 6\text{k}\Omega$		1	5	Ω
Output Capacitive Load	C_{load}	Output amplifier is optimized for the capacitive load range.	1		10	nF
Output Resistive Load (pull-down resistor)	R_{load}	Output resistive load for high linearity	6			k Ω
Output Short Circuit Current (Permanent)	I_{short}	Output shorted permanent to V_{dd} Output shorted permanent to GND		Not destroyed Not destroyed		
Output Leakage current	I_{leak}	High impedance mode ⁽¹⁾ $T_A = 150^{\circ}\text{C}$			20	μA
Linear Output Voltage Range V_{out} in [10% V_{dd} , 90% V_{dd}]	V_{out_pd}	pull-down $\geq 10\text{ k}\Omega$	10		90	% V_{dd}
High-impedance mode levels ⁽¹⁾	$V_{out_HiZ_pd}$	pull-down $R_L \leq 25\text{ k}\Omega$, $T \leq 125^{\circ}\text{C}$			5	% V_{dd}
Under-voltage detection ⁽²⁾	V_{dd_uvd}	Low to High Voltage	3.0	3.3	4.0	V
	V_{dd_uvh}	Hysteresis	0.2	0.3	0.45	V
Ratiometry enable detection	V_{ratio_d}	Low to High Voltage	4		4.5	V
	V_{ratio_h}	Hysteresis	0.01		0.5	V
Over-voltage detection ⁽²⁾	V_{dd_ovd}	Low to High Voltage	6.5		7.6	V
	V_{dd_ovh}	Hysteresis	0.05		0.7	V

Table 6: General electrical parameters

(1) Refer to section *Self-diagnostic*, Table 11.

(2) According to the following diagram:



10. Magnetic specification

Operating Parameters $T_A = -40^{\circ}\text{C}$ to 125°C , $V_{dd} = 4.5\text{V}$ to 5.5V , unless otherwise specified.

Parameter	Symbol	Test Conditions / Comments	Min	Typ	Max	Units
Magnetic field range	B		± 15		± 450	mT
Linearity Error	NL	V_{dd} in range [4.5V, 5.5V] V_{out} in [10% V_{dd} , 90% V_{dd}]	-0.4		+0.4	%FS
Programmable Sensitivity	S		5		150	mV/mT
Sensitivity programming Resolution	S_{res}			0.1		%

Table 7: Magnetic specification

10.1. Sensor active measurement direction

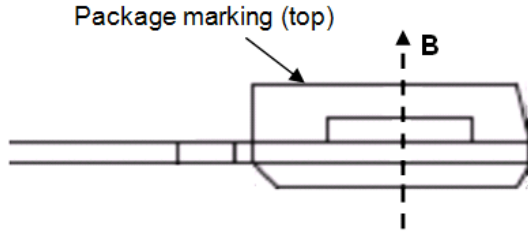


Figure 3: Magnetic Field Direction

11. Analog output specification

11.1. Timing specification

Operating Parameters $T_A = -40^\circ\text{C}$ to 125°C , $V_{DD} = 4.5\text{V}$ to 5.5V (unless otherwise specified).

Parameter	Symbol	Test Conditions / Comments	Min	Typ	Max	Units
Refresh rate	T_{rr}		0.8	1	2	μs
Step Response Time	T_{resp}	Delay between the input signal reaching 90% and the output signal reaching 90%, (2V step at the output, input rise time = $1\mu\text{s}$)				
		-Noise filter OFF		2	3	μs
		-Noise filter ON		7	9	μs
Bandwidth	BW	-Noise filter OFF		250		kHz
		-Noise filter ON		70		kHz
Power on Delay	T_{POD}	$V_{out} = 100\%$ of FS Pull-down resistor $\leq 100\text{k}\Omega$ During the Power-on delay, output will remain within the 10% fault band at all time.			1	ms
Ratiometry Cut-off Frequency	F_{ratio}			250		Hz

Table 8: Timing specification for high speed analog output

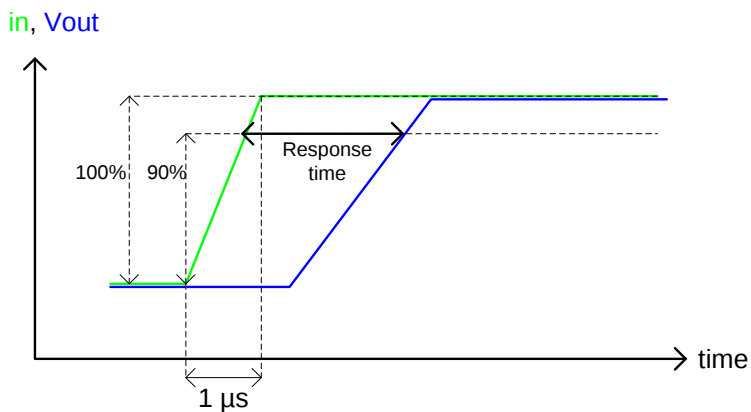


Figure 4: Response time definition

11.2. Accuracy specification

Operating Parameters $T_A = -40^{\circ}\text{C}$ to 125°C , $V_{dd} = 4.5\text{V}$ to 5.5V (unless otherwise specified).

Parameter	Symbol	Test Conditions	Min	Typ.	Max	Units
Thermal Offset Drift ⁽¹⁾	$\Delta^T\text{Voq}$	In ref. to $T = 35^{\circ}\text{C}$ $V_{dd} = 5\text{V}$ $\text{Voq} = 50 \pm 0.2 \%V_{dd}$	-10		10	mV
Thermal Sensitivity Drift	TC	In ref. to $T = 35^{\circ}\text{C}$ $V_{dd} = 5\text{V}$	-1.5	0	+1.5	% of S
RMS Output noise ⁽²⁾	N_{rms}	$S = 50\text{mV/mT}$				
		-Noise filter OFF			10	mVrms
		-Noise filter ON			6	mVrms
		$S = 7.3\text{mV/mT}$				
		-Noise filter OFF		2.8		mVrms
		-Noise filter ON		1.9		mVrms
Ratiometry Error Offset	ΔVoq	$\text{Voq} = 50\%V_{dd}$ $\Delta V_{dd} = 10\%V_{dd}$	-0.4		+0.4	% of Voq
Ratiometry Error Sensitivity	ΔS	$\Delta V_{dd} = 10\%V_{dd}$	-0.4		+0.4	% of S

Table 9: Accuracy specification for high speed analog output

- (1) Thermal offset drift specification is only valid when ENRATIO and PLATEPOL parameters are kept in their default configuration.
- (2) The RMS Output Noise depends on the factory sensitivity [mV/mT].

11.3. Remarks to the achievable accuracy

The achievable target accuracy depends on end-of-line calibration in the application. Resolution for offset calibration is better than $0.1\%V_{dd}$. Trimming capability is higher than measurement accuracy. End-of-line calibration can increase overall system accuracy.

12. Programmable items

12.1. Parameter table

Parameter	Bits	Factory Setting	Comment
VOQ[11:0]	12	trimmed	Quiescent output level (0 Gauss) adjustment
RG[2:0]	3	trimmed	Rough gain adjustment
FG[9:0]	10	trimmed	Fine gain adjustment
ENRATIO	1	1	Ratiometry enablement
TC1[7:0]	8	trimmed	Adjustment of the first order temperature compensation of the magnetic sensitivity
TC2HOT[4:0]	5	trimmed	Adjustment of the extra temperature compensation of the magnetic sensitivity at high temperature
TC2COLD[4:0]	5	trimmed	Adjustment of the extra temperature compensation of the magnetic sensitivity at low temperature
OFFDR2C[5:0]	6	trimmed	Adjustment of the offset drift at low temperature after the VGA
OFFDR2H[5:0]	6	trimmed	Adjustment of the offset drift at high temperature after the VGA
NOISEFILT ¹	1	0	0 : Noise filter deactivated
		1	1 : Noise filter enabled
ID[47:0]	48	Programmed	Melexis traceability ID

Table 10: Customer programmable items

12.2. Sensitivity programming (RG, FG)

The sensitivity can be programmed from 5 to 150 mV/mT, with the ROUGHGAIN (3 bits) and FINEGAIN (10 bits) parameters.

12.3. Offset / output quiescent voltage programming (VOQ)

The offset is programmable with 12 bits in 1.5 mV steps over the full output range. This corresponds to a calibration resolution of 0.03 %VDD. (The typical step would be $5V/4096 = 1.22$ mV, the actual step size can differ from the nominal value because of internal gain tolerance. The maximum step size of 1.5 mV is guaranteed).

Note: for optimal performance over temperature, VOQ should be programmed in the range 2 to 3V.

12.4. Output ratiometry (ENRATIO)

The ratiometry of the output versus the supply can be disabled by setting this bit to 0.

Note: for optimal performance over temperature, ratiometry should always be enabled (ENRATIO=1).

¹ Noise Filter enabled by default (NOISEFILT = 1) in MLX91209LVA-CAA-003. All other option codes use NOISEFILT = 0 in their default configuration

12.5. Sensitivity temperature drift programming (TC1, TC2COLD, TC2HOT)

First order sensitivity temperature drift can be trimmed from -2000 to 2000ppm/K with TC1. The programming resolution is 40ppm/K.

Second order sensitivity temperature drift can be trimmed from TC2COLD and TC2HOT. The programming resolution is 2ppm/K² for TC2COLD and 0.6ppm/K² for TC2HOT. The second order can also be seen as third order correction since cold and hot sides are independently adjusted.

Note: for optimal performance over temperature, the first order sensitivity drift compensation (TC1ST) should not exceed ± 500 ppm/K.

12.6. Offset temperature drift programming (OFFDR2C, OFFDR2H)

Offset temperature drift caused by the output amplifier can be compensated with these two parameters. This first order correction is done independently for temperatures over and below 25°C.

Note: two additional parameters (OFFDR1C, OFFDR1H) are calibrated by Melexis to compensate for the offset temperature drift caused by the Hall element (before the variable gain amplifier). These parameters should not be adjusted on customer-side.

12.7. Noise filter (NOISEFILT)

Setting this bit to 1 enables the noise filter, reducing noise and increasing response time.

12.8. Identification code (ID)

48 bits programmable identification code.

13. Self-diagnostic

The MLX91209 provides self-diagnostic features to detect internal memory errors and over- / under-voltage conditions. These features increase the robustness of the IC functionality, as they prevent erroneous output signal in case of internal or external failure modes.

Error	Action	Effect on Outputs	Remarks
Calibration Data CRC Error (at power up and in normal working mode)	Fault mode	High Impedance mode	Pull down resistive load => Diag Low
Power On delay		High Impedance mode	5ms max in high impedance followed by settling
Undervoltage Mode	IC is reset	High Impedance mode	300mV Hysteresis (typical)
Overvoltage detection	IC is reset	High Impedance mode	500mV Hysteresis (typical)

Table 11: Self diagnostic

14. Recommended Application Diagrams

14.1. Resistor and capacitor values

Part	Description	Value	Unit
C1	Supply capacitor, EMI, ESD	100	nF
C2	Decoupling, EMI, ESD	1-10 ⁽¹⁾	nF
R1	Pull-down resistor	6-100	kΩ

Table 12: Recommended Resistors and Capacitors Values

(1) 10nF is recommended for better EMC and ESD performance.

14.2. Pull down resistor for diagnostic low

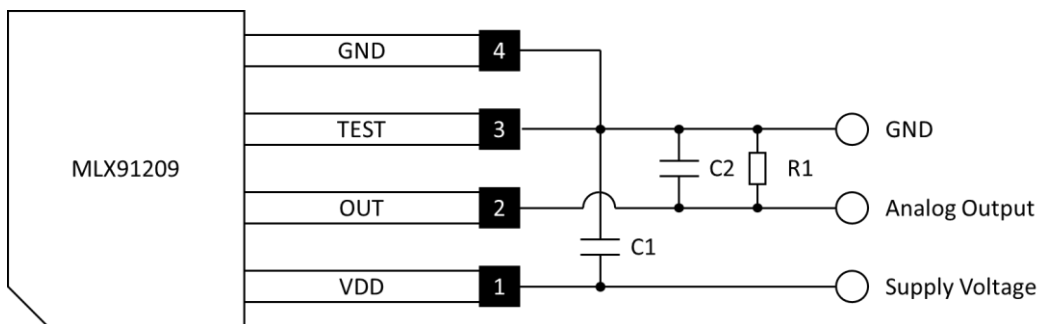


Figure 5: Diagnostic low

15. Typical performance

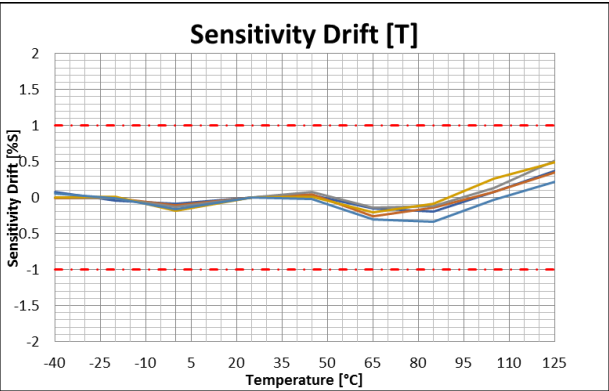


Figure 6: Thermal sensitivity drift.

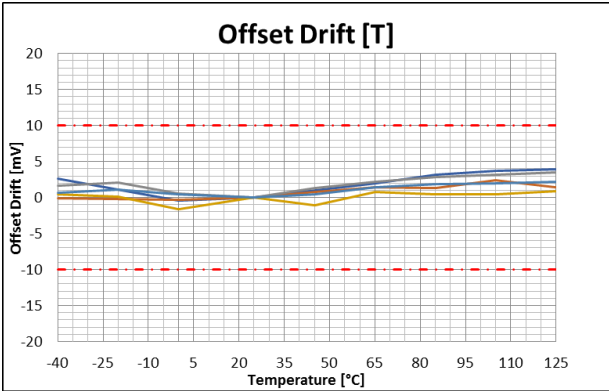


Figure 7: Thermal offset drift

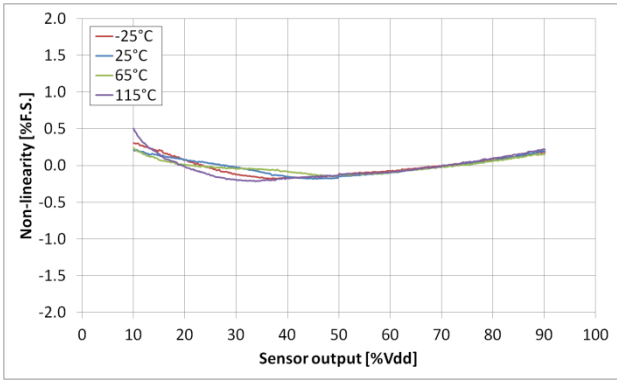


Figure 8: Non-linearity over temperature

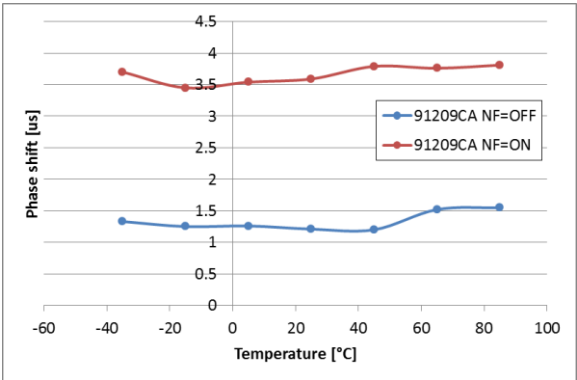


Figure 9: Phase shift over temperature.

16. IC handling and assembly

16.1. Storage and handling of plastic encapsulated ICs

Plastic encapsulated ICs shall be stored and handled according to their MSL categorization level (specified in the packing label) as per J-STD-033.

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD). The component assembly shall be handled in EPA (Electrostatic Protected Area) as per ANSI S20.20

For more information refer to Melexis [*Guidelines for storage and handling of plastic encapsulated ICs*](#) ⁽²⁾

16.2. Assembly of encapsulated ICs

For Surface Mounted Devices (SMD, as defined according to JEDEC norms), the only applicable soldering method is reflow.

For Through Hole Devices (THD), the applicable soldering methods are reflow, wave, selective wave and robot point-to-point. THD lead pre-forming (cutting and/or bending) is applicable under strict compliance with Melexis [*Guidelines for lead forming of SIP Hall Sensors*](#) ⁽²⁾.

Melexis products soldering on PCB should be conducted according to the requirements of IPC/JEDEC and J-STD-001. Solder quality acceptance should follow the requirements of IPC-A-610.

For PCB-less assembly refer to the relevant application notes ⁽²⁾ or contact Melexis.

Electrical resistance welding or laser welding can be applied to Melexis products in THD and specific PCB-less packages following the [*Guidelines for welding of PCB-less devices*](#) ⁽²⁾.

Environmental protection of customer assembly with Melexis products for harsh media application, is applicable by means of coating, potting or overmolding considering restrictions listed in the relevant application notes ⁽²⁾

For other specific process, contact Melexis via www.melexis.com/technical-inquiry

² www.melexis.com/ic-handling-and-assembly

17. FAQ

For which current range can the sensor be used?

The magnetic field [mT] seen by the sensor for a given current [A] depends on the design of the enclosing ferromagnetic core (air gap size, material type, etc.). Therefore, the current range is not limited by the sensor itself, but rather by the magnetic properties of the core (saturation, hysteresis, etc.).

What is the default sensitivity of the sensor?

The sensor is factory calibrated for a typical sensitivity of 50mV/mT.

How can I program the sensor?

The sensor uses a 3 wires communication protocol (Vdd, GND and Out) and can be programmed using Melexis Universal Programmer (PTC-04), with the dedicated daughter board PTC04-DB-HALL05. For more information, please visit www.melexis.com/PTC-04.

18. Package Information

18.1. Package Marking & Hall Plate Position

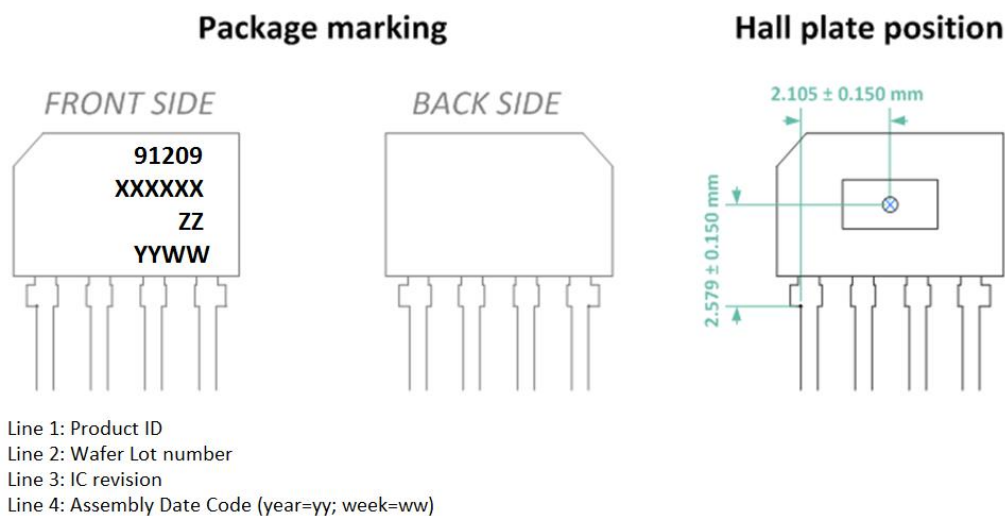
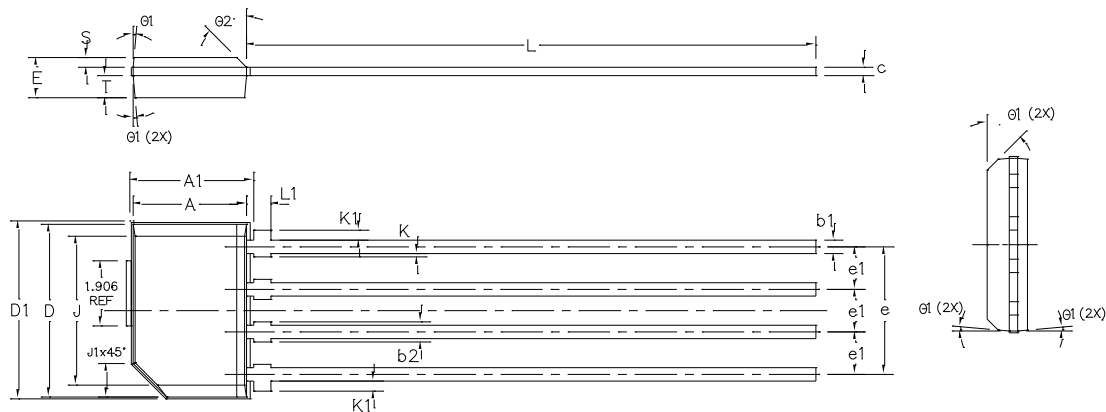


Figure 10: VA/SIP 4L Package Marking and Hall Plate Position

18.2. VA / SIP 4L (single in-line package)



SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	3.30	3.38	3.46
A1	3.63	3.71	3.79
D	5.08	5.16	5.24
D1	5.33	5.38	5.43
E	1.10	----	1.20
J	4.10	4.30	4.50
J1	1.00 REF		
K	0.00	----	0.15
K1	0.25	0.30	0.35
L	17.5	18.0	18.5
L1	0.48	0.53	0.58
S	0.24	----	0.29
T	0.61	----	0.66
b1	0.35	----	0.48
b2	0.40	----	0.60
c	0.18	----	0.34
e	3.76	----	3.86
e1	1.22	1.27	1.32
θ1	5° REF		
θ2	45° REF		

Note:

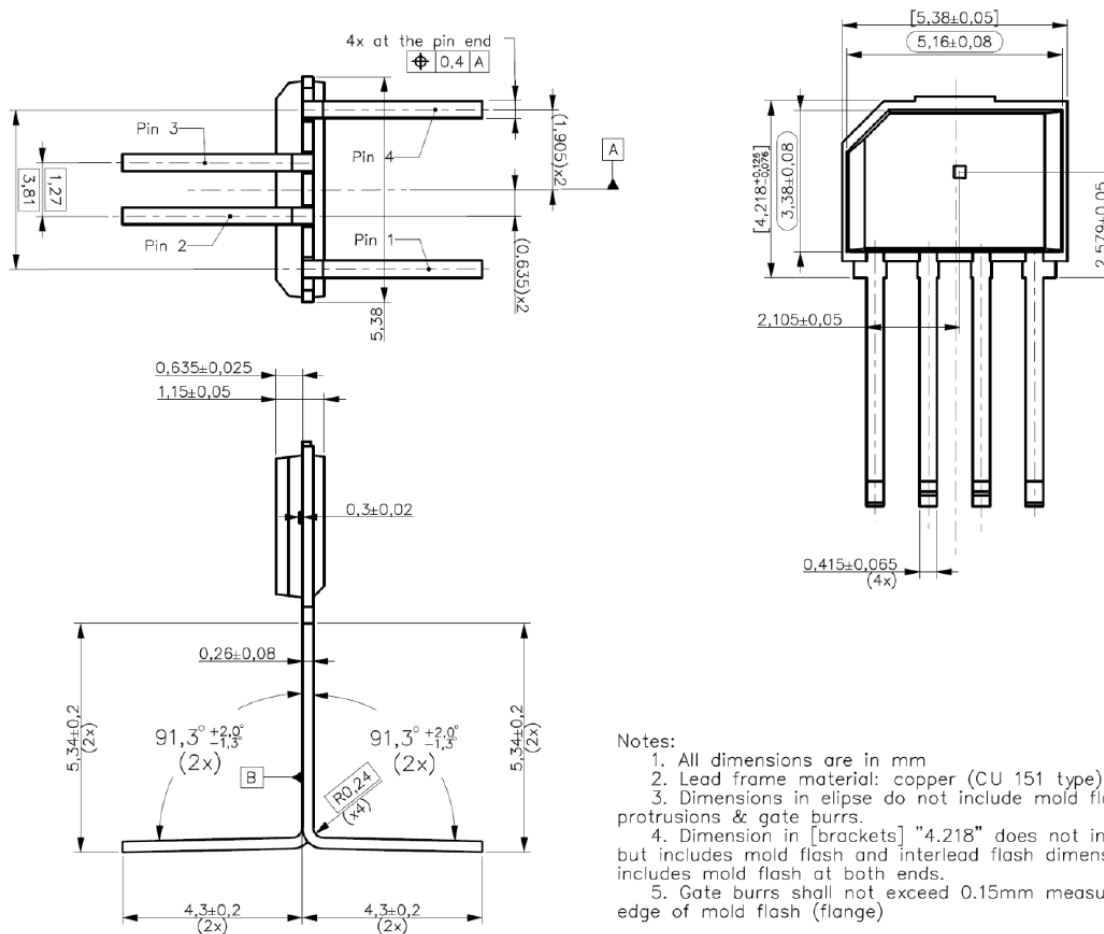
1. DIMENSIONS "A" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS AND GATE BURRS.
2. DIMENSIONS "A1" DOES NOT INCLUDE GATE BURRS BUT INCLUDES MOLD FLASH AT BOTH ENDS.
3. MOLD GATE BURRS SHALL NOT EXCEED 0.15 mm MEASURED FROM EDGE OF MOLD FLASH (FLANGE).
4. DIMENSION "D1" INCLUDES MOLD FLASH AT BOTH ENDS.
5. LEAD PLATING; MATTE TIN PLATING THICKNESS 7.62 - 15.42 μm .

18.3. Trim and form type: 90° 2x2x91.3 (h=5.34mm); Bending-STD2 (CAR-xxx)

MLX91209

Hall Current Sensor IC in VA package

Datasheet

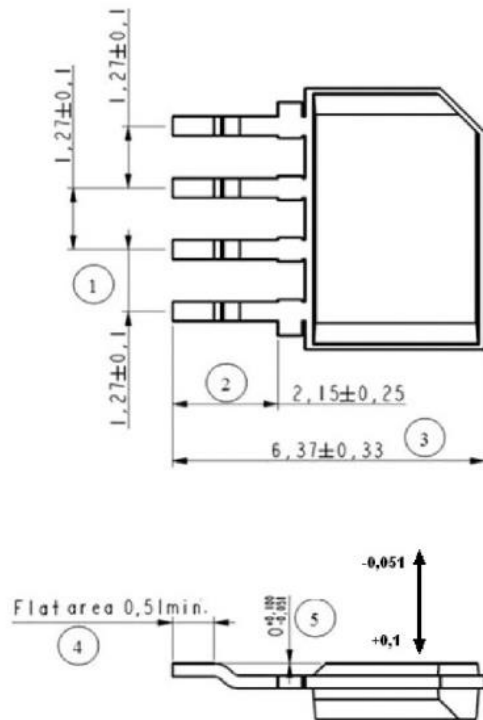


18.4. Trim and form type: SMD style TFT4K1 (CAZ-xxx)

MLX91209

Hall Current Sensor IC in VA package

Datasheet



Parameter				
Dim# 1 [mm]	Dim# 2 [mm]	Dim# 3 [mm]	Dim# 4 [mm]	Dim# 5 [mm]
1.27 +/- 0.10	2.15 +/- 0.25	6.37 +/- 0.33	min. 0.51	0 -0.051/+0.10

19. Disclaimer

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